

SCHOTTKY RECTIFIER

80 Amp



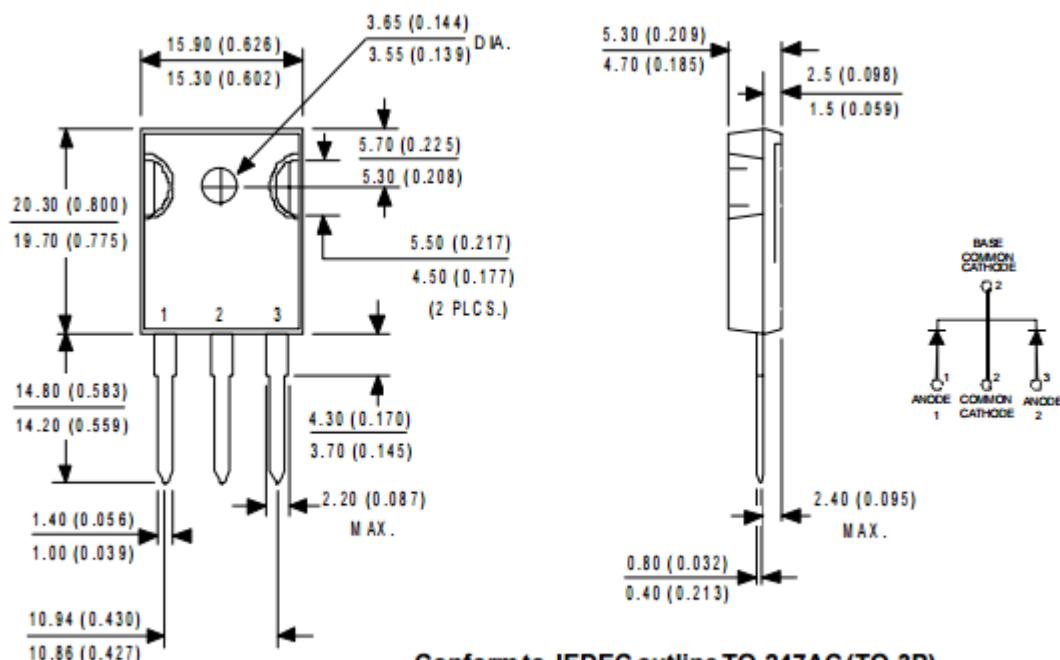
Description/Features

Major Ratings and Characteristics

Characteristics	Values	Units
I _{F(AV)} Rectangular waveform	80	A
V _{RRM}	20	V
I _{FSM} @tp=5μssine	2200	A
V _F @40Apk, T _J =150°C (perleg)	0.32	V
T _J range	-55to150	°C

This center tap Schottky rectifier has been optimized for ultra low forward voltage drop specifically for 3.3V output power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

- 150 °C T_J operation
- Center tap configuration
- Optimized for 3.3V application
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



Conform to JEDEC outline TO-247AC (TO-3P)

Dimensions in millimeters and inches

Voltage Ratings

Part number	80CPQ020		
V_R Max. DC Reverse Voltage (V)	20		

Absolute Maximum Ratings

Parameters	Values	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current (Per Leg) (Per Device)	40	A	50% duty cycle @ $T_C = 138^\circ\text{C}$, rectangular wave form
	80		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current (Per Leg)	2200	A	5μs Sine or 3μs Rect. pulse
	500		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy (Per Leg)	27	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 6$ Amps, $L = 1.5\text{mH}$
I_{AR} Repetitive Avalanche Current (Per Leg)	6	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	Values	Units	Conditions
V_{FM} Max. Forward Voltage Drop (Per Leg) (1)	0.46	V	$T_J = 25^\circ\text{C}$
	0.55	V	$T_J = 125^\circ\text{C}$
	0.36	V	$T_J = 150^\circ\text{C}$
	0.46	V	
	0.32	V	
	0.43	V	
I_{RM} Max. Reverse Leakage Current (Per Leg) (1)	5.5	mA	$V_R = \text{rated } V_R$
	1100	mA	
	110	mA	$V_R = 5\text{V}$
	600	mA	$V_R = 10\text{V}$
$V_{F(TO)}$ Threshold Voltage	0.185	V	$T_J = T_J \text{ max.}$
r_f Forward Slope Resistance	3.2	mΩ	
C_T Max. Junction Capacitance (Per Leg)	6500	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25°C
L_s Typical Series Inductance (Per Leg)	7.5	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs	

(1) Pulse Width < 300μs, Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	Values	Units	Conditions
T_J Max. Junction Temperature Range	-55 to 150	°C	
T_{stg} Max. Storage Temperature Range	-55 to 150	°C	
R_{thJC} Max. Thermal Resistance Junction to Case (Per Leg)	0.6	°C/W	DC operation
R_{thJC} Max. Thermal Resistance Junction to Case (Per Package)	0.3	°C/W	DC operation
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.25	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	6(0.21)	g(oz.)	
T Mounting Torque	Min.	6(5)	Kg-cm (lbf-in)
	Max.	12(10)	
Case Style	TO-247AC(TO-3P)		JEDEC

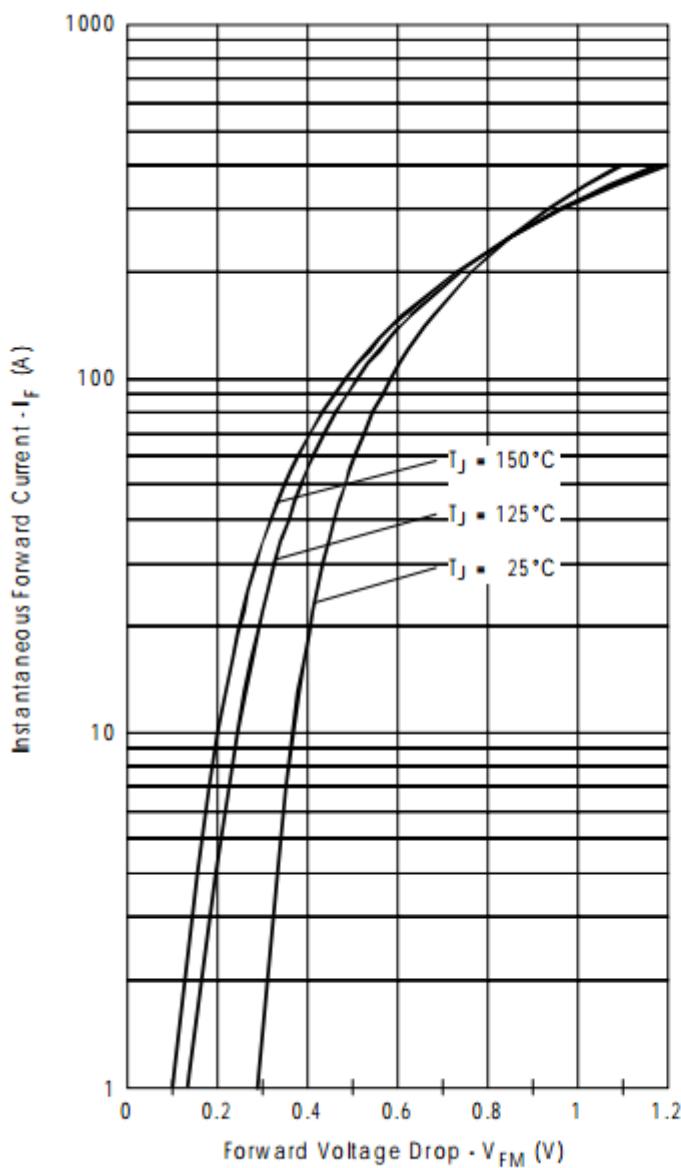


Fig.1-Max. Forward Voltage Drop Characteristics
(PerLeg)

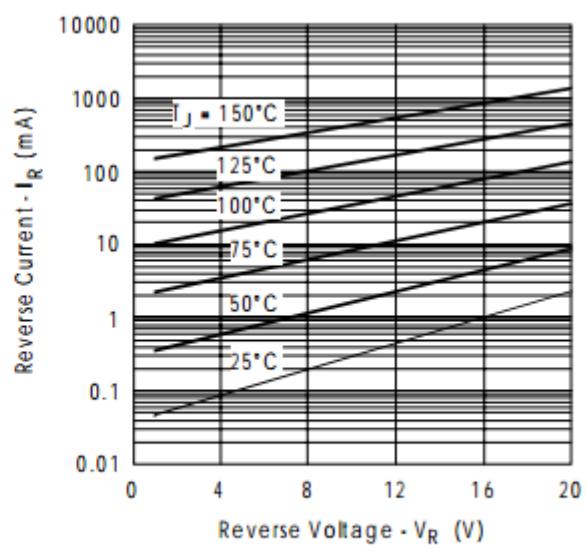


Fig.2-Typical Values Of Reverse Current
Vs. Reverse Voltage (PerLeg)

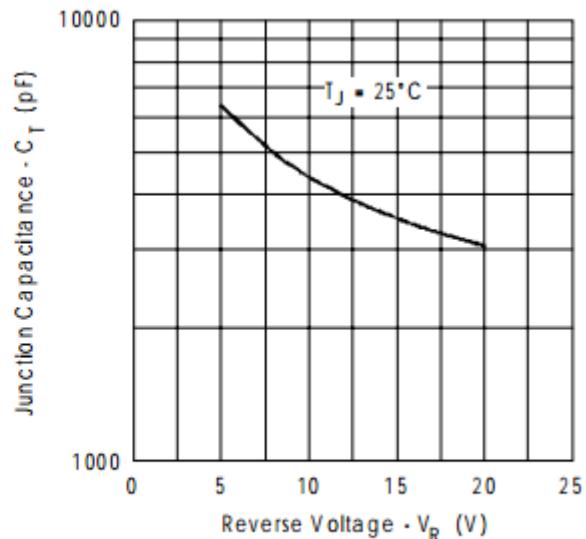


Fig.3-Typical Junction Capacitance
Vs. Reverse Voltage (PerLeg)

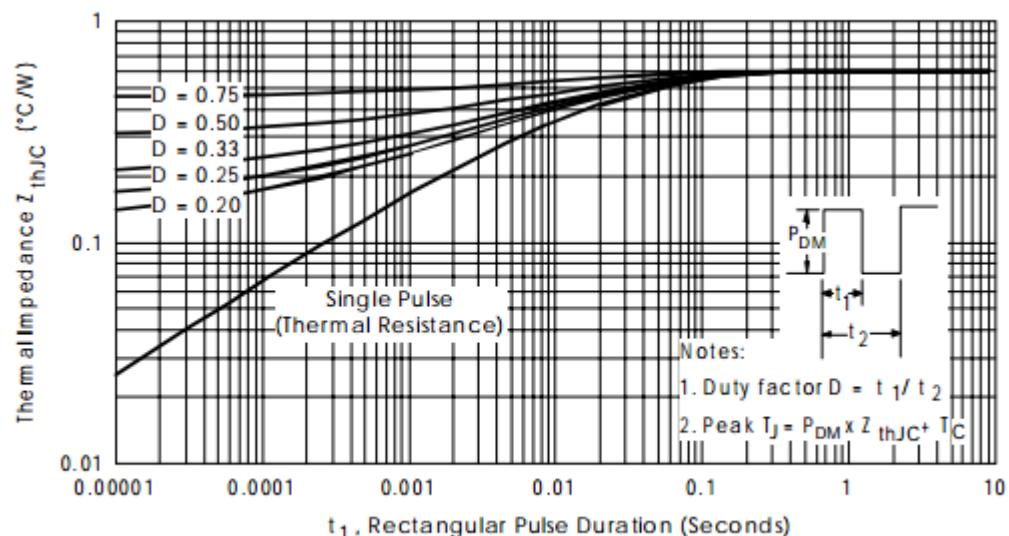


Fig.4-Max. Thermal Impedance Z_{thJC} Characteristics (PerLeg)

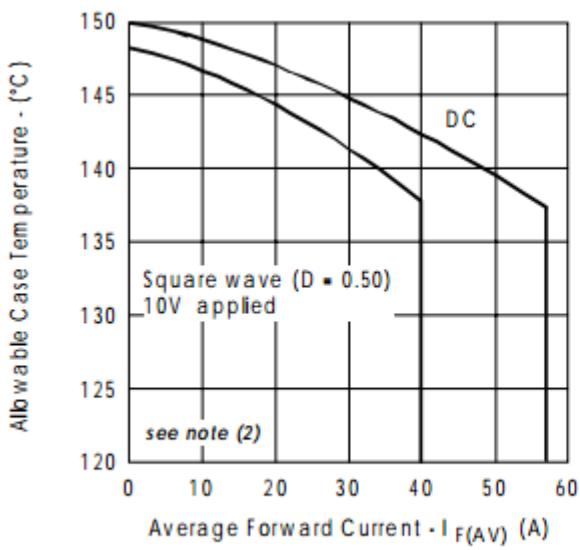


Fig.5-Max. Allowable Case Temperature Vs. Average Forward Current (PerLeg)

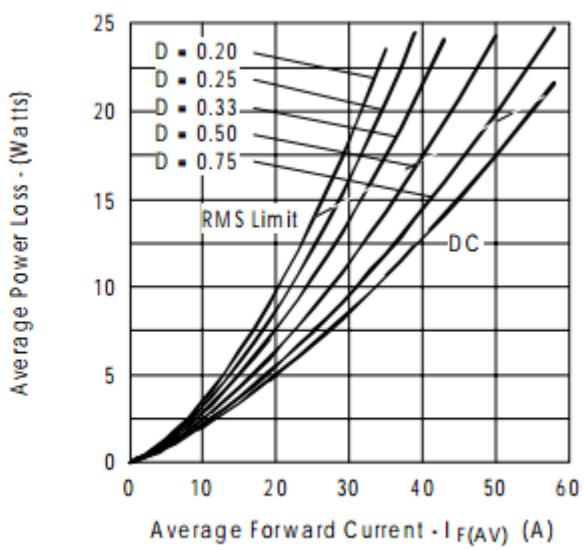


Fig.6-Forward Power Loss Characteristics (PerLeg)

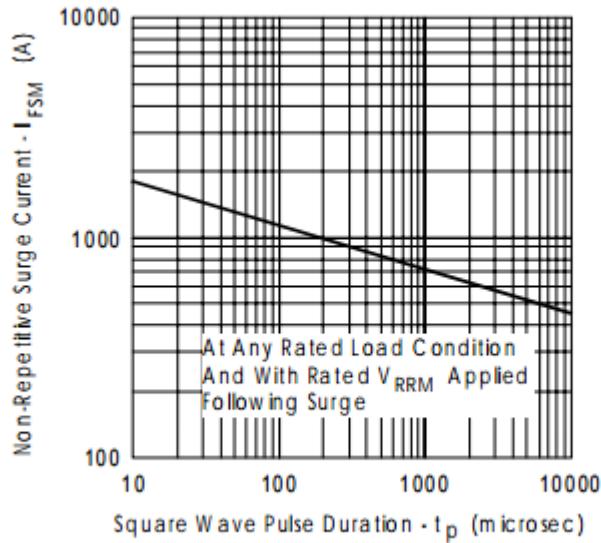


Fig.7-Max. Non-Repetitive Surge Current (PerLeg)

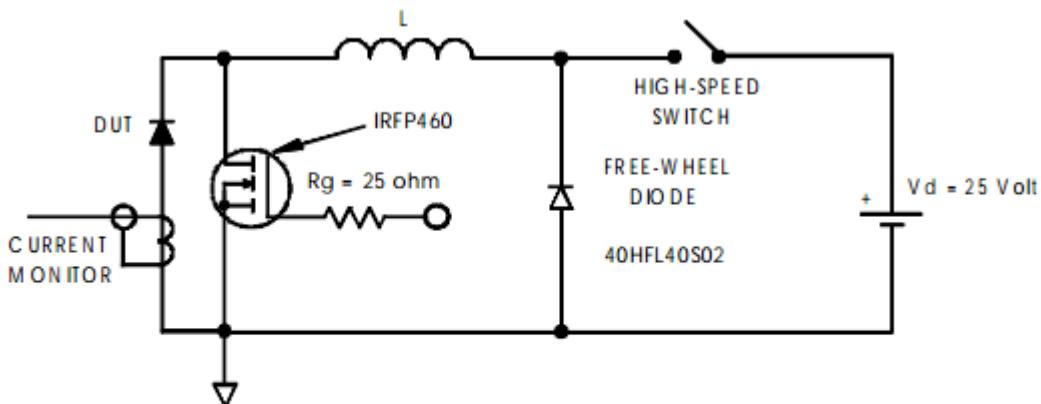


Fig.8-Unclamped Inductive Test Circuit

- (2) Formula used: $T_C = T_J - (P_d + P_{d,REV}) \times R_{thJC}$;
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $P_{d,REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 10V$